

P-CHANNEL MOS FIELD EFFECT TRANSISTOR  
 FOR SWITCHING

DESCRIPTION

The  $\mu$ PA1812 is a switching device which can be driven directly by a 4.0-V power source.

The  $\mu$ PA1812 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- ★ Can be driven by a 4.0-V power source
  - ★ Low on-state resistance
- $R_{DS(on)1} = 39 \text{ m}\Omega \text{ MAX. (} V_{GS} = -10 \text{ V, } I_D = -2.5 \text{ A)}$   
 $R_{DS(on)2} = 63 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -2.5 \text{ A)}$   
 $R_{DS(on)3} = 69 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.0 \text{ V, } I_D = -2.5 \text{ A)}$

ORDERING INFORMATION

PART NUMBER	PACKAGE
$\mu$ PA1812GR-9JG	Power TSSOP8

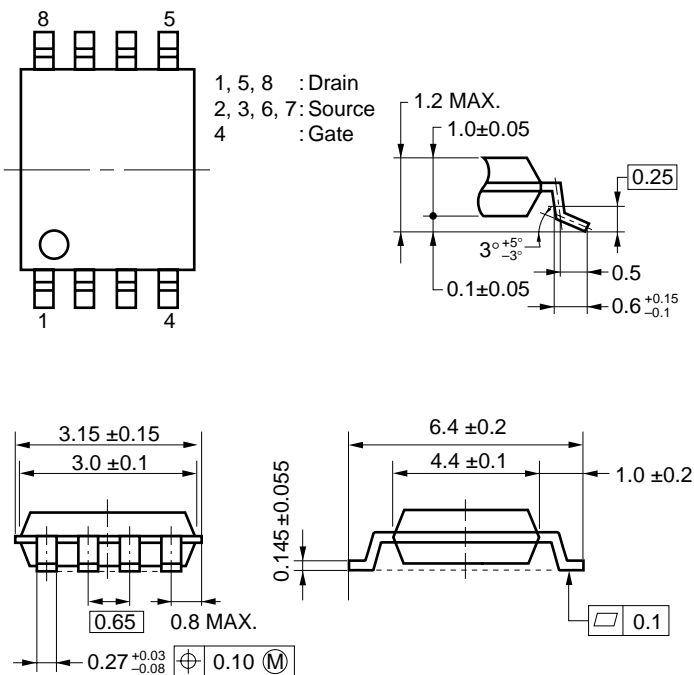
ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Drain to Source Voltage	$V_{DSS}$	-30	V
Gate to Source Voltage	$V_{GSS}$	-20/+5	V
Drain Current (DC)	$I_{D(DC)}$	$\pm 5.0$	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	$\pm 20$	A
Total Power Dissipation <sup>Note2</sup>	$P_T$	2.0	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

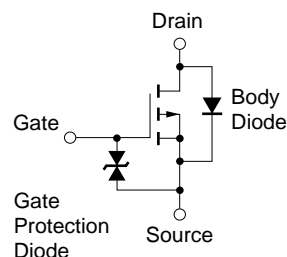
- Notes 1.  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$   
 2. Mounted on ceramic substrate of  $5000 \text{ mm}^2 \times 1.1 \text{ mm}$

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

PACKAGE DRAWING (Unit : mm)



EQUIVALENT CIRCUIT

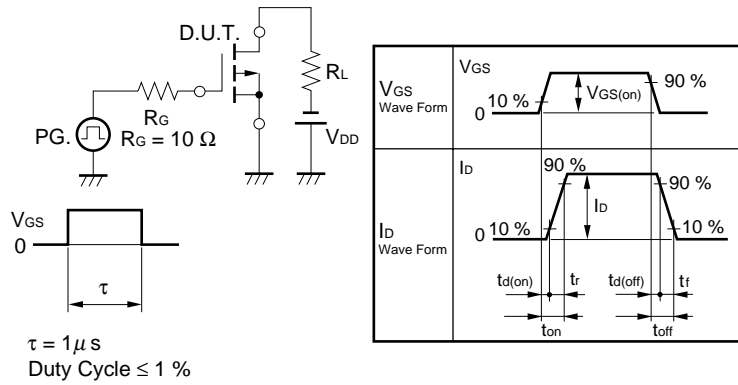


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 Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

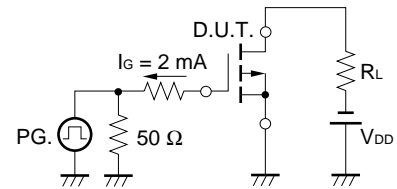
★ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = -30 V, V <sub>GS</sub> = 0 V			-10	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA	-1.0	-1.6	-2.5	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -2.5 A	1	8		S
Drain to Source On-state Resistance	R <sub>DS(on)1</sub>	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -2.5 A		29	39	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -2.5 A		46	63	mΩ
	R <sub>DS(on)3</sub>	V <sub>GS</sub> = -4.0 V, I <sub>D</sub> = -2.5 A		52	69	mΩ
Input Capacitance	C <sub>iSS</sub>	V <sub>DS</sub> = -10 V		1500		pF
Output Capacitance	C <sub>oSS</sub>	V <sub>GS</sub> = 0 V		550		pF
Reverse Transfer Capacitance	C <sub>rSS</sub>	f = 1 MHz		270		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = -10 V		30		ns
Rise Time	t <sub>r</sub>	I <sub>D</sub> = -2.5 A		160		ns
Turn-off Delay Time	t <sub>d(off)</sub>	V <sub>GS(on)</sub> = -10 V		110		ns
Fall Time	t <sub>f</sub>	R <sub>G</sub> = 10 Ω		80		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DS</sub> = -24 V		31		nC
Gate to Source Charge	Q <sub>GS</sub>	I <sub>D</sub> = -5.0 A		4		nC
Gate to Drain Charge	Q <sub>GD</sub>	V <sub>GS</sub> = -10 V		8		nC
Diode Forward Voltage	V <sub>F(S-D)</sub>	I <sub>F</sub> = 5.0 A, V <sub>GS</sub> = 0 V		0.76		V

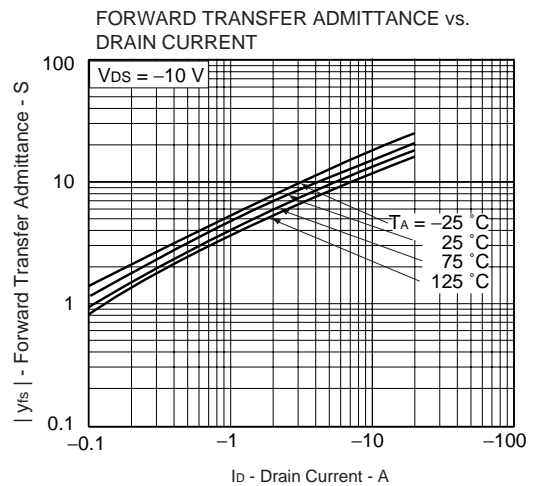
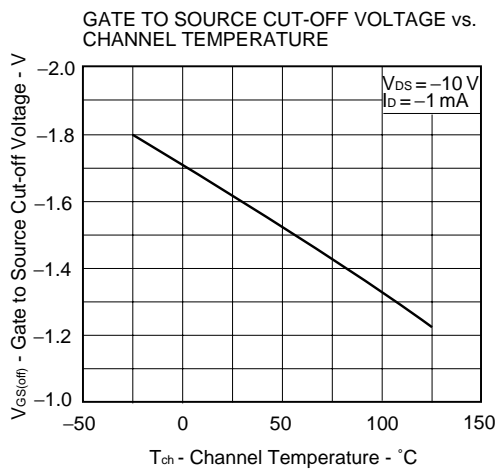
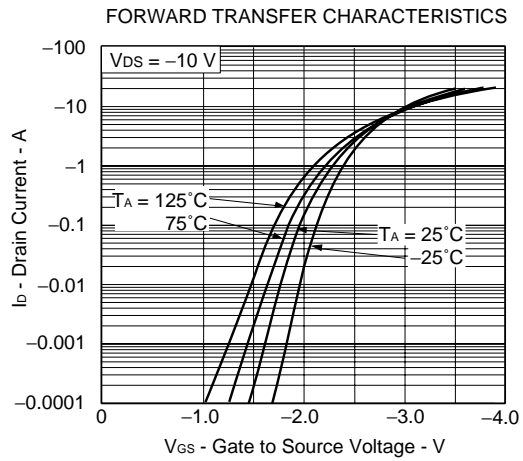
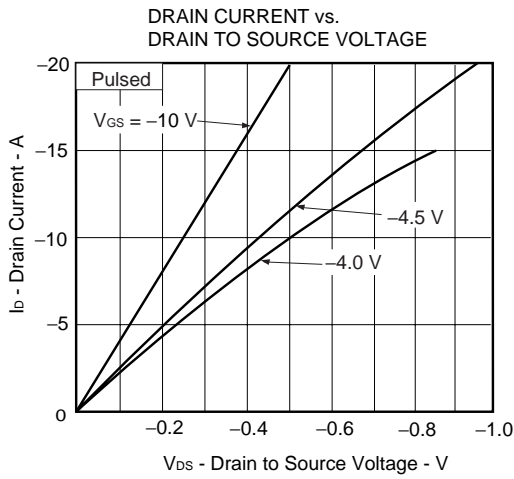
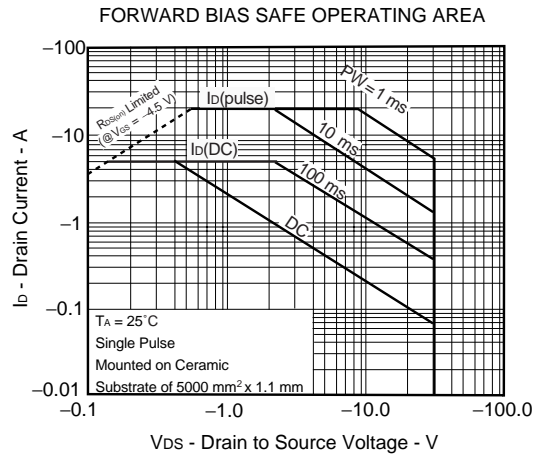
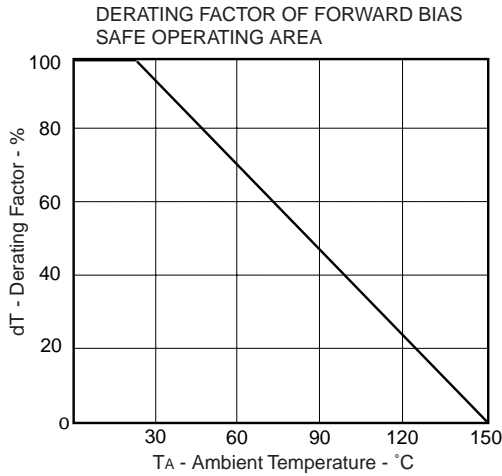
TEST CIRCUIT 1 SWITCHING TIME

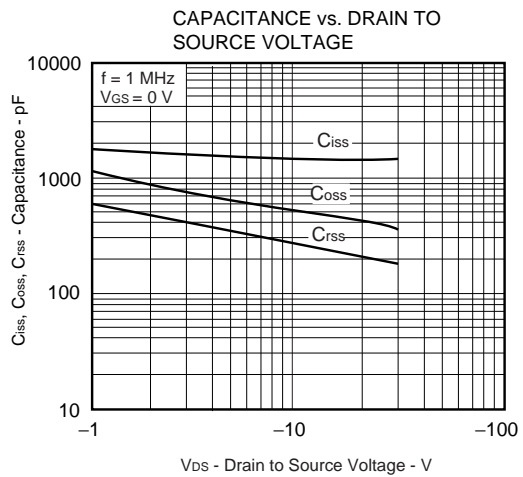
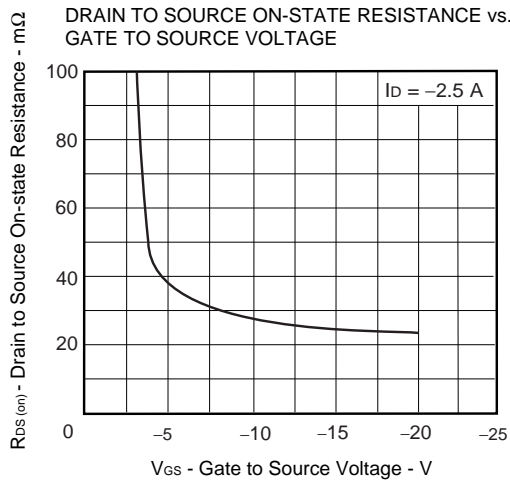
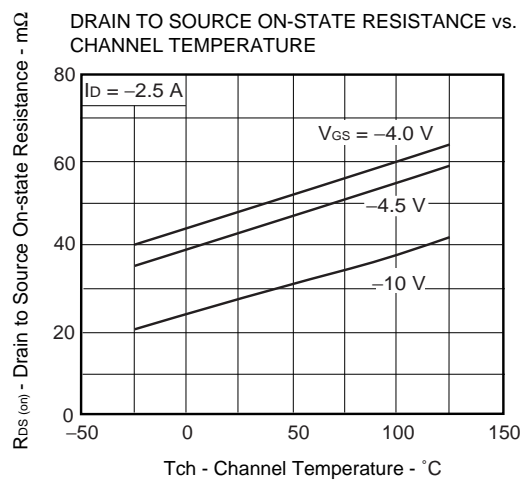
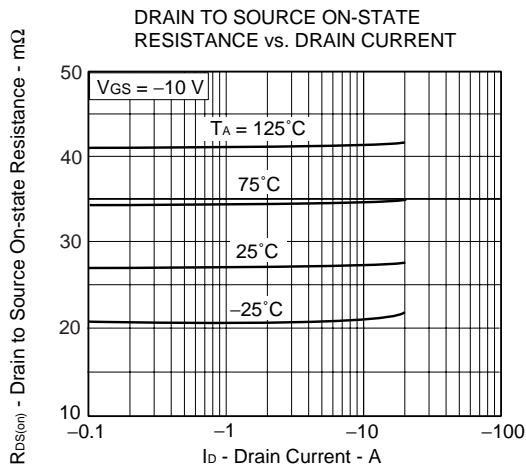
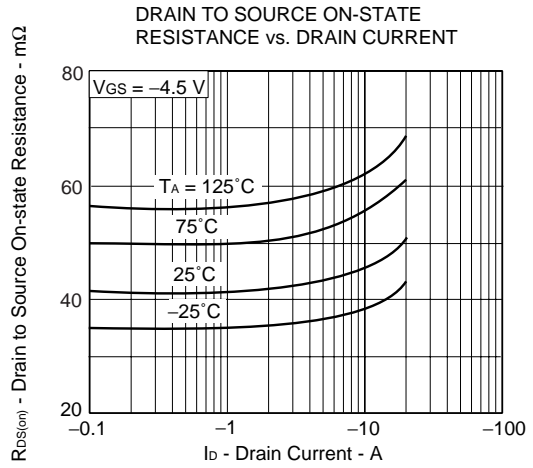
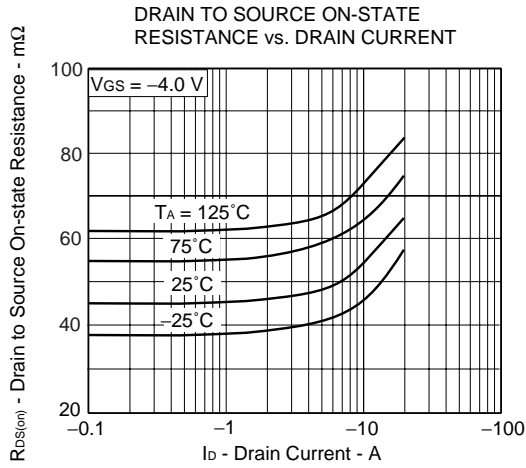


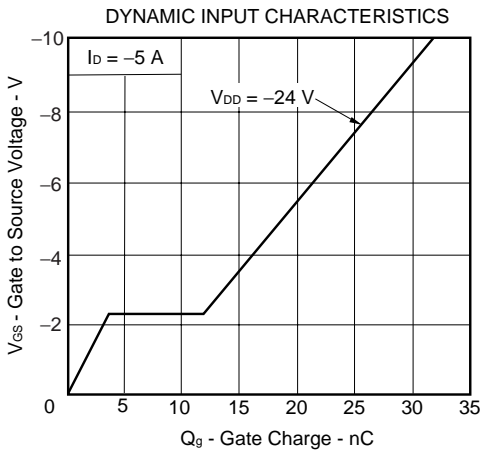
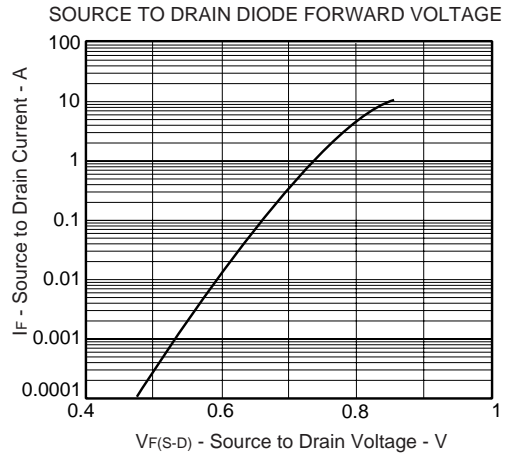
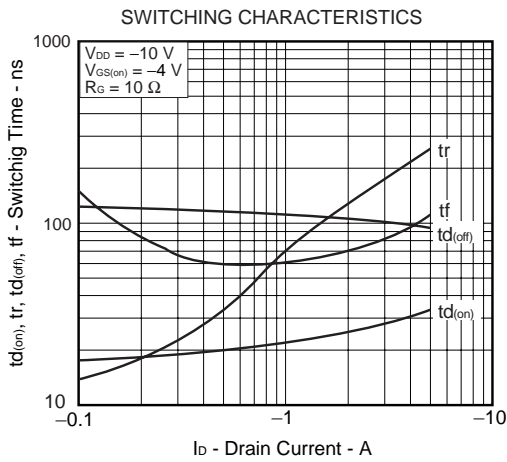
TEST CIRCUIT 2 GATE CHARGE



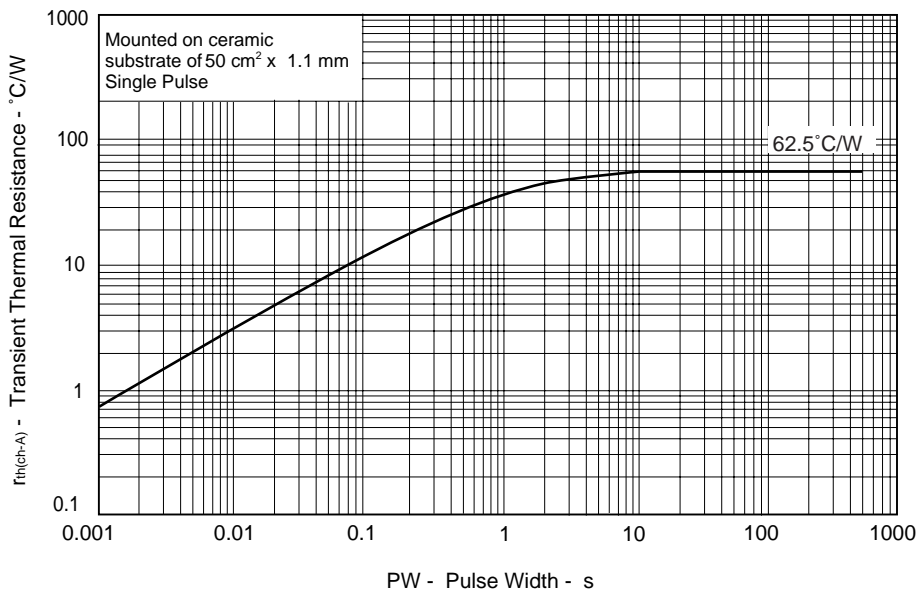
★ TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)







TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



[MEMO]

[MEMO]

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